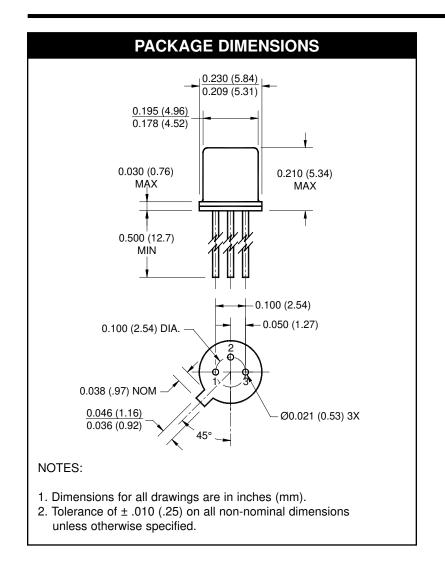
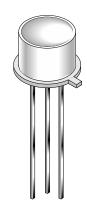
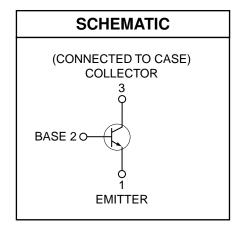
L14C1 L14C2







DESCRIPTION

The L14C1/L14C2 are silicon phototransistors mounted in a wide angle, TO-18 package.

FEATURES

- · Hermetically sealed package
- · Wide reception angle



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ABSOLUTE MAXIMUM RATINGS (T _A = 25°C unless otherwise specified)								
Parameter	Symbol	Rating	Unit					
Operating Temperature	T _{OPR}	-65 to +125	°C					
Storage Temperature	T _{STG}	-65 to +150	°C					
Soldering Temperature (Iron)(3,4,5 and 6)	T _{SOL-I}	240 for 5 sec	°C					
Soldering Temperature (Flow)(3,4 and 6)	T _{SOL-F}	260 for 10 sec	°C					
Collector to Emitter Breakdown Voltage	V _{CEO}	50	V					
Collector to Base Breakdown Voltage	V_{CBO}	50	V					
Emitter to Base Breakdwon Voltage	V _{EBO}	7	V					
Power Dissipation (T _A = 25°C) ⁽¹⁾	P _D	300	mW					
Power Dissipation (T _C = 25°C) ⁽²⁾	P _D	600	mW					

NOTE:

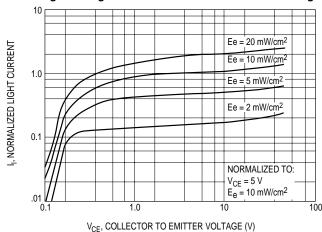
- 1. Derate power dissipation linearly 3.00 mW/°C above 25°C ambient.
- 2. Derate power dissipation linearly 6.00 mW/°C above 25°C case.
- 3. RMA flux is recommended.
- 4. Methanol or isopropyl alcohols are recommended as cleaning agents.
- 5. Soldering iron tip 1/16" (1.6mm) minimum from housing.
- 6. As long as leads are not under any stress or spring tension.
- 7. Light source is a GaAs LED emitting light at a peak wavelength of 940 nm.
- 8. Figure 1 and figure 2 use light source of tungsten lamp at 2870°K color temperature. A GaAs source of 3.0 mW/cm² is approximately equivalent to a tungsten source, at 2870°K, of 10 mW/cm².

ELECTRICAL / OPTICAL CHARACTERISTICS (TA =25°C) (All measurements made under pulse conditions)							
PARAMETER	TEST CONDITIONS	SYMBOL	MIN	TYP	MAX	UNITS	
Collector-Emitter Breakdown	$I_{\rm C} = 10 \text{ mA}, \text{ Ee} = 0$	BV _{CEO}	50		_	V	
Emitter-Base Breakdown	$I_E = 100 \mu A, Ee = 0$	BV _{EBO}	7.0		_	V	
Collector-Base Breakdown	$I_{C} = 100 \mu A, Ee = 0$	BV _{CBO}	50		_	V	
Collector-Emitter Leakage	V _{CE} = 20 V, Ee = 0	I _{CEO}	_		100	nA	
Reception Angle at 1/2 Sensitivity		θ		±40		Degrees	
On-State Collector Current L14C1	Ee = 0.5 mW/cm ² , $V_{CE} = 5 V^{(7,8)}$	I _{C(ON)}	.16		_	mA	
On-State Collector Current L14C2	Ee = 0.5 mW/cm ² , $V_{CE} = 5 V^{(7,8)}$	I _{C(ON)}	.08		_	mA	
On-State Collector Current L14C2	Ee = 1.0 mW/cm ² , $V_{CE} = 5 V^{(7,8)}$	I _{C(ON)}	.16		_	mA	
Turn-On Time	I_{C} = 2 mA, V_{CC} = 10 V, R_{L} =100 Ω	t _{on}		5		μs	
Turn-Off Time	I_{C} = 2 mA, V_{CC} = 10 V, R_{L} =100 Ω	t _{off}		5		μs	
Saturation Voltage	$I_{\rm C} = 0.40$ mA, Ee = 6.0 mW/cm ^{2(7,8)}	$V_{CE(SAT)}$			0.40	V	



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Figure 1. Light Current vs. Collector to Emitter Voltage



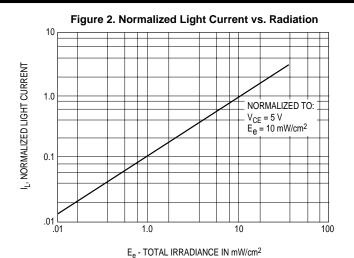
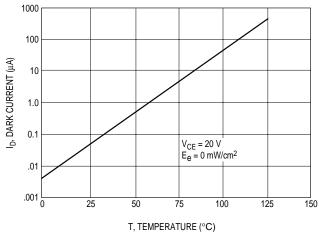


Figure 3. Dark Current vs. Temperature



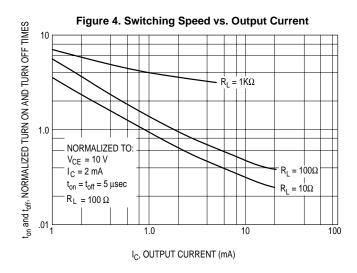


Figure 5. Spectral Response

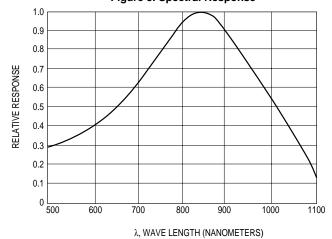
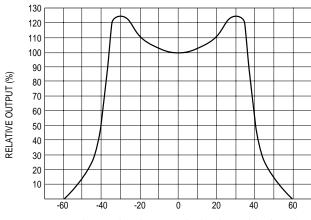


Figure 6. Angular Response Curve



θ, ANGULAR DISPLACEMENT FROM OPTICAL AXIS (DEGREES)



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